

Parameter	Value
V <sub>CEO</sub>	-30V
Ι <sub>C</sub>	-1.0A

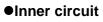
#### Features

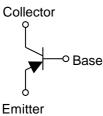
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SD2703, 2SD2675
- 3) Low V<sub>CE(sat)</sub>

 $V_{CE(sat)} = -0.35V(Max.)$ 

 $(I_C/I_B = -500 \text{mA}/ -25 \text{mA})$ 

4) Lead Free/RoHS Compliant.





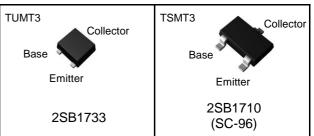
Packaging specifications

# Applications

Motor driver , LED driver Power supply

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1733	TUMT3	2021	TL	180	8	3,000	EW
2SB1710	TSMT3	2928	TL	180	8	3,000	EW

#### Outline



### •Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V <sub>CBO</sub>	-30	V
Collector-emitter voltage		V <sub>CEO</sub>	-30	V
Emitter-base voltage		V <sub>EBO</sub>	-6	V
Collector current	DC	۱ <sub>C</sub>	-1.0	А
	Pulsed	I <sub>CP</sub> <sup>*1</sup>	-2.0	А
Dower dissinction	2SB1733	P <sub>D</sub> *2	0.4	W
Power dissipation	2SB1710	P <sub>D</sub> <sup>*2</sup>	0.5	W
Junction temperature		Tj	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +150	°C

\*1 Pw=1ms , single pulse

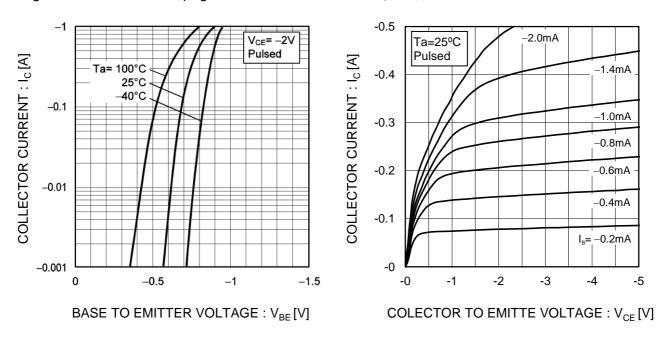
\*2 Each terminal mounted on a reference land

## •Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	$BV_{CBO}$	$I_{C} = -10 \mu A$	-30	-	-	V
Collector-base breakdown voltage	$BV_{CEO}$	I <sub>C</sub> = -1mA	-30	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	I <sub>E</sub> = -10μΑ	-6	-	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -30V$	-	-	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -6V	-	-	-100	nA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{C} = -500 \text{mA}, I_{B} = -25 \text{mA}$	-	-150	-350	mV
DC current gain	h <sub>FE</sub> *3	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	-	680	-
Transition frequency	$f_{T}^{*3}$	$V_{CE} = -2V, I_E = 100 \text{mA}$ f=100MH <sub>Z</sub>	-	400	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_E = 0A$ f = 1MHz	-	7	-	pF

\*3 Pulsed

#### •Electrical characteristic curves(Ta = 25°C)

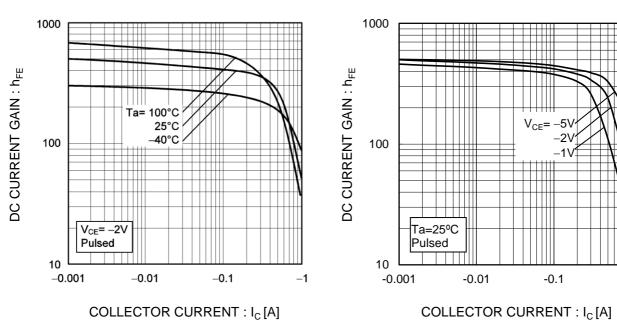


#### Fig.1 Ground Emitter Propagation Characteristics

Fig.3 DC Current Gain vs. Collector Current(I)

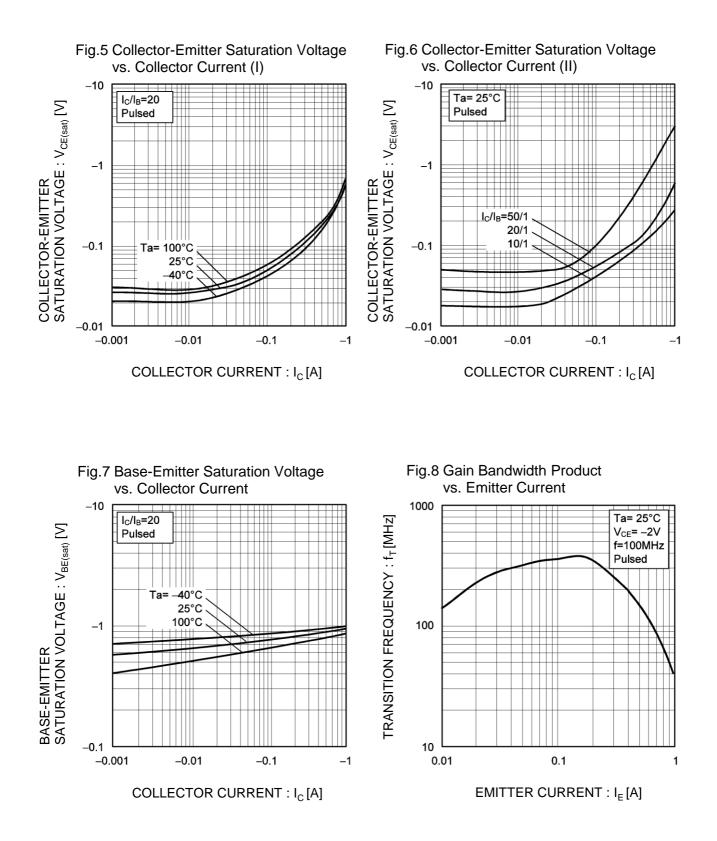
Fig.4 DC Current Gain vs. Collector Current(II)

Fig.2 Typical Output Characteristics



-1

#### •Electrical characteristic curves(Ta = 25°C)



#### •Electrical characteristic curves(Ta = 25°C)

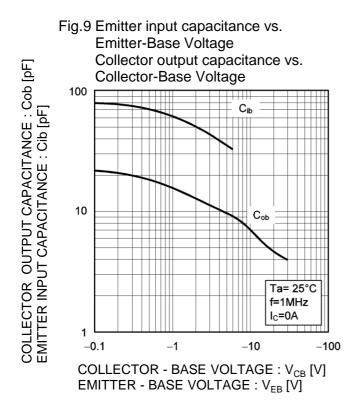
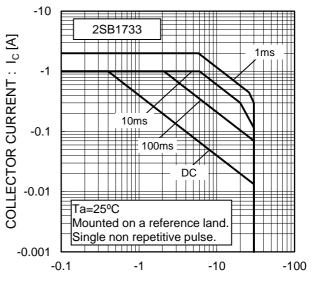
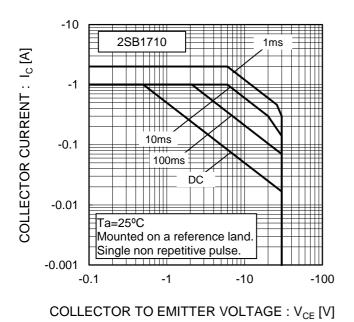


Fig.10 Safe Operating Area



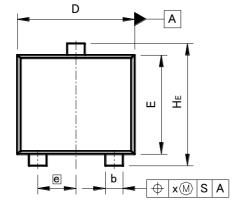
COLLECTOR TO EMITTER VOLTAGE :  $V_{CE}$  [V]

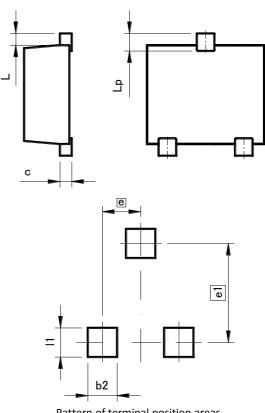
Fig.11 Safe Operating Area

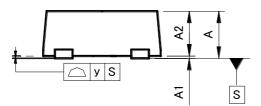


#### •Dimensions (Unit : mm)

TUMT3







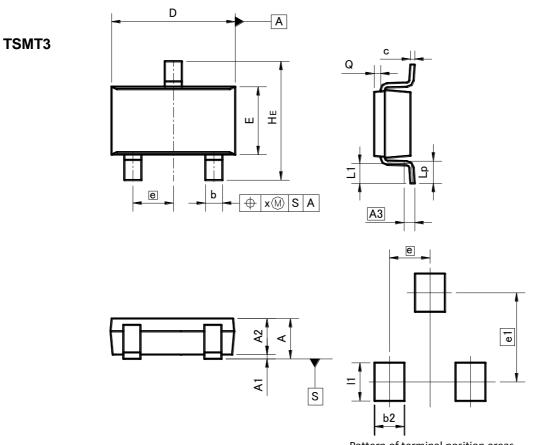
Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A	-	0.85	-	0.033
A1	0.00	0.10	0.000	0.004
A2	0.72	0.82	0.028	0.032
b	0.25	0.40	0.010	0.016
с	0.12	0.22	0.005	0.009
D	1.90	2.10	0.075	0.083
E	1.60	1.80	0.063	0.071
е	0.	65	0.026	
HE	2.00	2.20	0.079	0.087
L	0.20		0.0	08
Lp	_	0.40	_	0.016
x	_	0.10	-	0.004
У	_	0.10	_	0.004

DIM		ETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
b2	-	0.50	-	0.020
e1	1.70		0.0	067
1	-	0.50	-	0.020

Dimension in mm / inches

#### •Dimensions (Unit : mm)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
А	-	1.00	-	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.:	25	0.0	10
b	0.35	0.50	0.014	0.020
с	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
е	0.9	95	0.0	37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
x	_	0.20	_	0.008

DIM	MILIM	IETERS INCH		HES
DIM	MIN	MAX	MIN	MAX
b2		0.70	-	0.028
e1	2.10		0.0	83
1	-	0.90	-	0.035

Dimension in mm / inches

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